

CPC3981Z

800V, 45Ω N-Channel Depletion-Mode MOSFET

$V_{(BR)DSX}$	$R_{DS(on)}$	I_{DSS}	Package
800V	45Ω	100mA	SOT-223-2L

Features

- High Breakdown Voltage: 800V
- Low On-Resistance: 45Ω max.
- Low $V_{GS(off)}$: -1.4V to -3.1V
- High Input Impedance
- Small Package Size: SOT-223-2L

Applications

- Normally-On Switches
- Solid State Relays
- Converters
- Telecommunications
- Power Supply
- Current Regulators

Description

The CPC3981Z is an 800V, N-channel, depletion-mode, Field Effect Transistor (FET) in a modified SOT-223 package to provide greater separation of the drain and source leads for high voltage applications.

Fabricated using Littelfuse Integrated Circuits' proprietary vertical DMOS process yields a robust MOSFET device with high input impedance and high voltage performance.

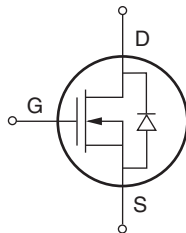
The CPC3981Z's highly reliable MOSFET has been used extensively in Littelfuse Integrated Circuits' Solid State Relays in power, industrial, and telecommunications applications.

The CPC3981Z is available in the SOT-223-2L package.

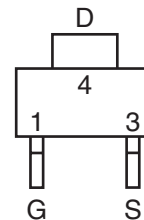
Ordering Information

Part #	Description
CPC3981ZTR	SOT-223-2L: Tape and Reel (3000/Reel)

Circuit Symbol



Package Pinout



Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Drain-to-Source Voltage	800	V
Gate-to-Source Voltage	±15	V
Pulsed Drain Current	150	mA
Total Package Dissipation ¹	1.8	W
Operational Temperature	-55 to +125	°C
Junction Temperature, Maximum	+125	°C
Storage Temperature	-55 to +125	°C

¹ Mounted on 1"x1" 2 oz. Copper FR4 board.

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.

Electrical Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Drain-to-Source Breakdown Voltage	$V_{(BR)DSX}$	$V_{GS} = -5.5V, I_D = 1\mu A$	800	-	-	V
Gate-to-Source Off Voltage	$V_{GS(off)}$	$V_{DS} = 15V, I_D = 1\mu A$	-1.4	-	-3.1	V
Change in $V_{GS(off)}$ with Temperature	$dV_{GS(off)}/dT$	$V_{DS} = 15V, I_D = 1\mu A$	-	-	-6.3	mV/°C
Gate Body Leakage Current	I_{GSS}	$V_{GS} = \pm 15V, V_{DS} = 0V$	-	-	100	nA
Drain-to-Source Leakage Current	$I_{D(off)}$	$V_{GS} = -5.5V, V_{DS} = 800V$	-	-	1	μA
Saturated Drain-to-Source Current	I_{DSS}	$V_{GS} = 0V, V_{DS} = 15V$	100	-	-	mA
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$V_{GS} = 0V, I_D = 100mA$	-	32.5	45	Ω
Change in $R_{DS(on)}$ with Temperature	$dR_{DS(on)}/dT$		-	-	2.5	%/°C
Forward Transconductance	g_{fs}	$I_D = 50mA, V_{DS} = 10V$	100	-	-	m Ω
Input Capacitance	C_{ISS}	$V_{GS} = -3.5V$	-	105	-	pF
Common Source Output Capacitance	C_{OSS}	$V_{DS} = 25V$	-	7.5	-	
Reverse Transfer Capacitance	C_{RSS}	$f = 1MHz$	-	2.75	-	
Source-Drain Diode Voltage Drop	V_{SD}	$V_{GS} = -5.5V, I_{SD} = 100mA$	-	0.67	0.95	V

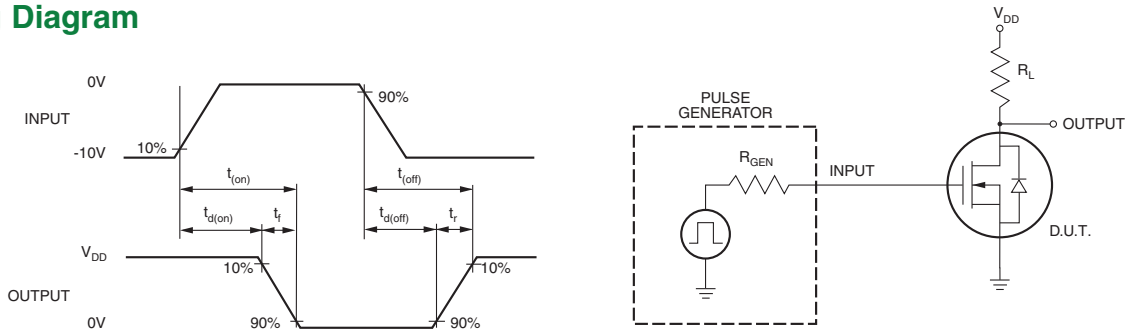
Timing Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 25V, I_D = 50mA, V_{GS} = 0V \text{ to } -10V,$ $R_{GEN} = 50\Omega$	-	79.2	170	ns
Fall Time	t_f			34.9	145	
Turn-Off Delay Time	$t_{d(off)}$			25.3	65	
Rise Time	t_r			19.7	35	

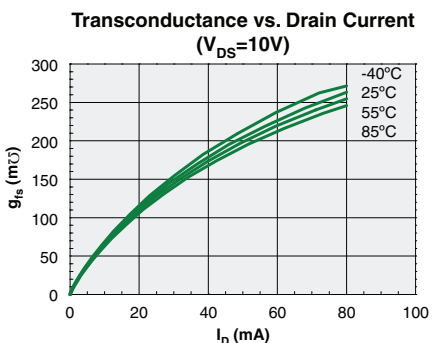
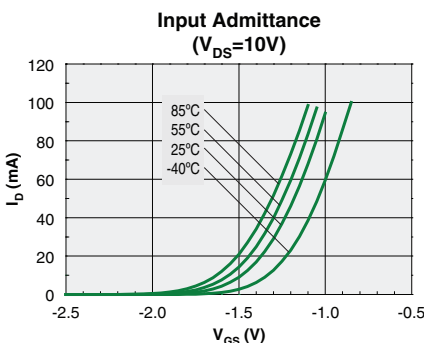
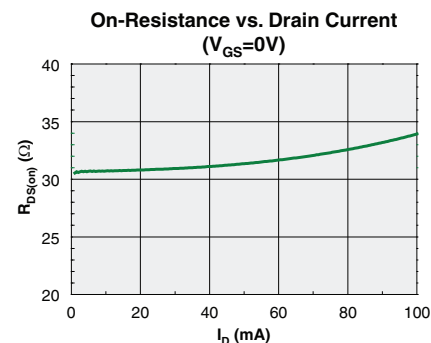
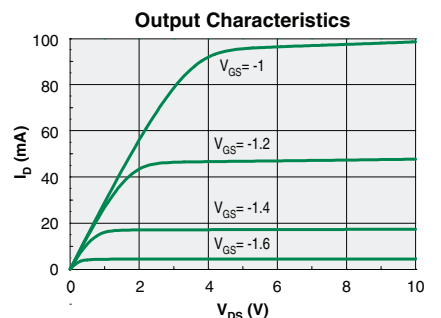
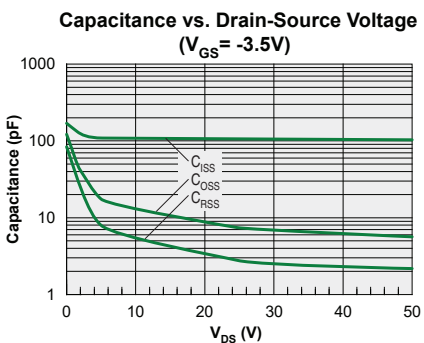
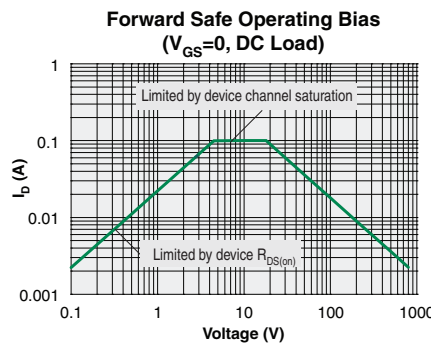
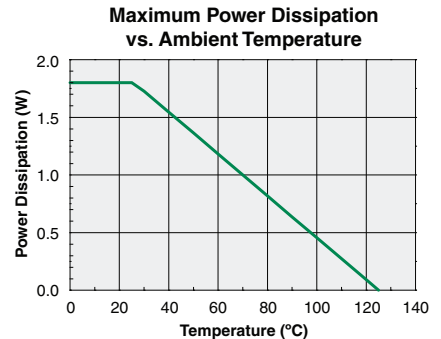
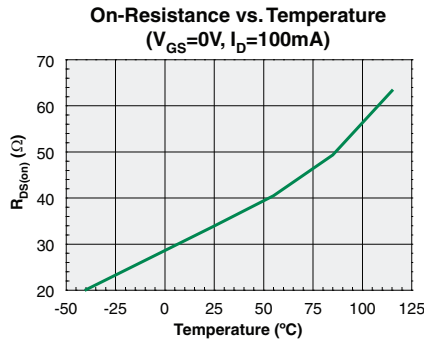
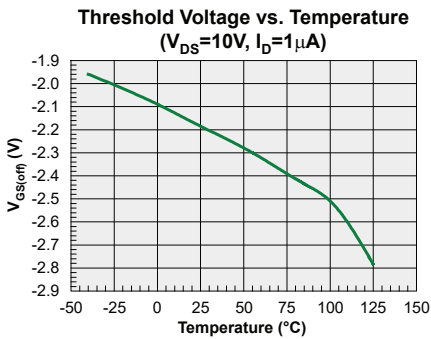
Thermal Characteristics

Parameter	Symbol	Rating	Units
Thermal Resistance			
Junction to Ambient	Θ_{JA}	55	°C/W
Junction to Case	Θ_{JC}	23	

Timing Diagram



PERFORMANCE DATA*



*Unless otherwise noted, data presented in these graphs is typical of device operation at 25°C.

Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. Littelfuse Integrated Circuits classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
CPC3981Z	MSL 3

ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard **JESD-625**.

Soldering Profile

Provided in the table below is the **IPC/JEDEC J-STD-020** Classification Temperature (T_C) and the maximum total dwell time (t_p) in all reflow processes that the body temperature of these surface mount devices may be ($T_C - 5$)°C or greater. The device's body temperature must not exceed the Classification Temperature at any time during reflow soldering processes.

Device	Classification Temperature (T_C)	Dwell Time (t_p)	Max Reflow Cycles
CPC3981Z	260°C	30 seconds	3

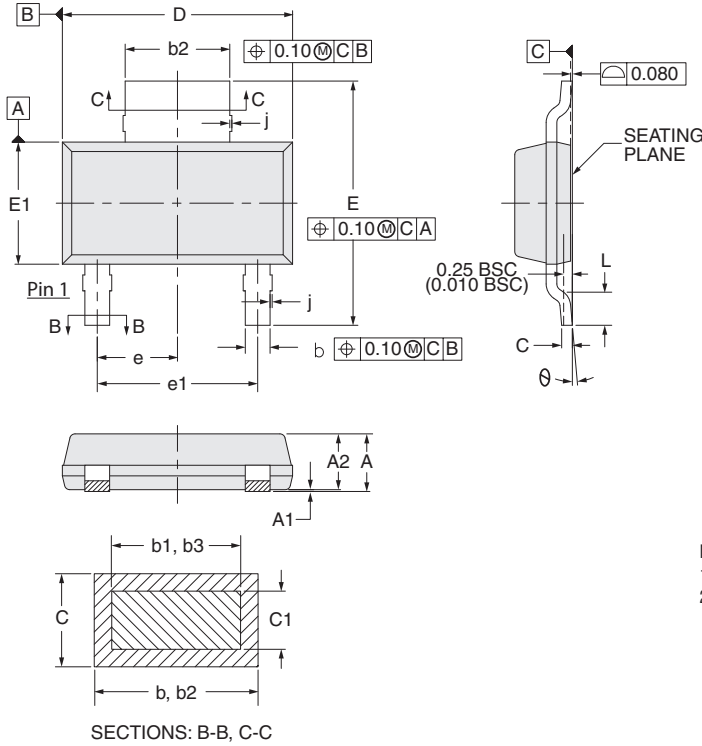
Board Wash

Littelfuse Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.



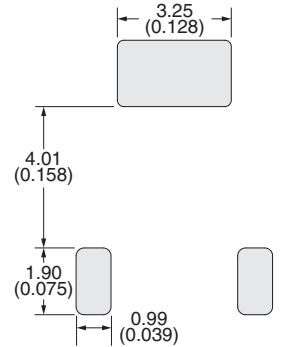
Mechanical Dimensions

CPC3981Z



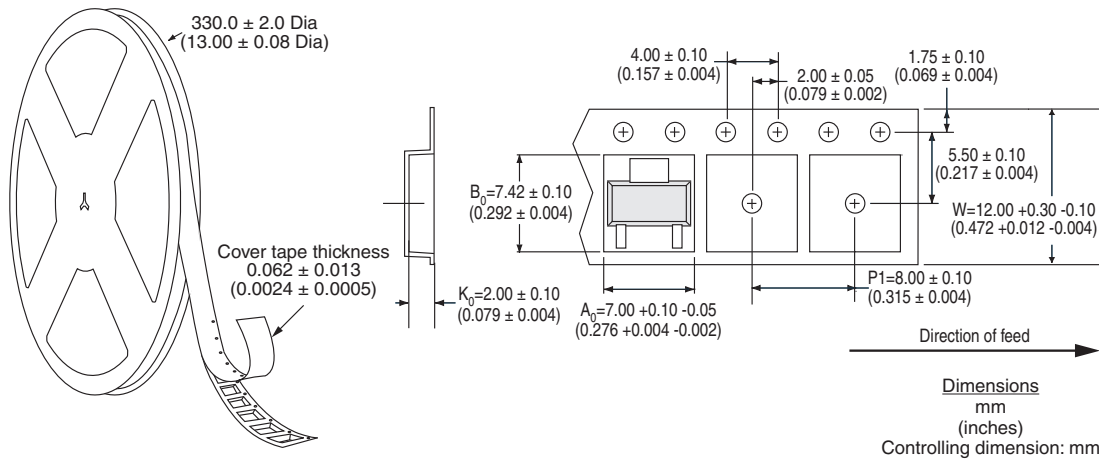
SYMBOL	COMMON			
	MM		INCH	
	MIN	MAX	MIN	MAX
A	-	1.80	-	0.071
A1	0.02	0.10	0.001	0.004
A2	1.50	1.70	0.059	0.067
b	0.66	0.84	0.026	0.033
b1	0.60	0.79	0.024	0.031
b2	2.90	3.10	0.114	0.122
b3	2.84	3.05	0.112	0.120
c	0.23	0.35	0.009	0.014
c1	0.23	0.33	0.009	0.013
D	6.30	6.70	0.248	0.264
E	6.70	7.30	0.264	0.287
E1	3.30	3.70	0.130	0.146
e	2.30 BSC.		0.091 BSC.	
e1	4.60 BSC.		0.182 BSC.	
L	0.81	1.10	0.032	0.043
θ	0°	10°	0°	10°
j	-	0.13	-	0.005

Recommended PCB Land Pattern



- Notes:
1. Controlling dimension: mm
 2. Dimensions D and E1 are specified at the outermost edges of the plastic body exclusive of mold flash, burrs, and interlead flash.

CPC3981ZTR Tape & Reel



For additional information please visit our website at: <https://www.littelfuse.com>



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